## **BIO-DATA**

# **Summary:**

Dr. Amitesh Kumar has been working in the area of semiconductor devices for applications in Memory, Solar Cells, Biosensors, Power Electronics etc, since 2014.

He has **36 SCI journals** with **4 Patents** (**2 granted**, 2 published) along with 12 International and 24 National conferences papers and 11 book chapters. **2 PhD students** have submitted thesis under his guidance. **1 DST project of 29 Lacs** running and 2 ISRO projects in communication. List of Publications is attached.

His works have been published in reputed SCI journals, including 6 works on IEEE Transactions. Recently, one of his works on synaptic devices was accepted in IEEE Transactions on Electron Devices. **Device Engineering of Dual Metal Gate-based Artificial Synapse for Enhanced Plasticity utilizing Al2O3 based Ion Conducting Electrolyte.** 

Dr. Amitesh Kumar has done his B.Tech in Electrical Engineering from Indian Institute of Technology, BHU .He did his Ph.D. in Electrical Engineering from Indian Institute of Technology, Indore. He did his Postdoc Research from University of Utah, USA and Indian Institute of Technology, Kanpur.

He has been a Research Fellow awardee from **CSIR**, **Govt. of India**. He is currently working as Assistant Professor in Electrical Engineering at National Institute of Technology, Patna.

He has been awarded SCJP, CCNA, CCNP, ACP by respective organisations. He has also been recipient of multiple research awards for Best Presentation, DST & CSIR International Travel Support etc.

#### **Research Interests:**

Semiconductor devices for applications in Memory, Solar Cells, Biosensors, Power Electronics Neuromorphic Computing

## 1. Name and full correspondence address with contact details

## Dr. Amitesh Kumar

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**Google Scholar:** https://scholar.google.co.in/citations?user=IIQ7ERIAAAAJ&hl=en&authuser=2

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# 2. Institution: National Institute of Technology (NIT), Patna, India

## 3. Academic Qualification

#### Education

S/N	Degree	Year	Subject	University/ Institution	% of Marks
1.	B. Tech	May, 2009	Electrical Engineering	Indian Institute of Technology, BHU	CPI 7.4

**B. Tech Project title:** Study of Cluster Based Routing Protocol for Mobile Adhoc Networks (MANETS) And performance comparison of pro-active and reactive protocol

Name of Project Supervisor (s) and his affiliation			1. Prof. S.C. Gupta, Electrical Engineering, IIT-BHU scgupta.eee@iitbhu.ac.in, scgupta_bhu@yahoo.com https://www.researchgate.net/profile/Suresh Gupta5		
2.	XII	May, 2004	English, Mathematics, Physics, Chemistry	BSEB	73.8 %
3.	X	May, 2002	English, Hindi, Mathematics, Science, Social Science, Computer studies	ICSE	92.6 %

## 8. Ph.D thesis title, Guide's Name, Institute/Organization/University, Year of Award.

S/N	Degree	Year	Subject	University/ Institution	% of Marks
1.	Ph. D.	May, 2019	Electrical Engineering	Indian Institute of Technology, Indore	CPI 7.82

**Ph.D thesis title:** Fabrication and modelling of ZnO based resistive switching devices for non-volatile memory applications

Name of Thesis Supervisor (s) and their affiliation

- Dr. Shaibal Mukherjee, Electrical Engineering, IIT Indore shaibal@iiti.ac.in <a href="http://www.iiti.ac.in/people/~shaibal/leader.php">http://www.iiti.ac.in/people/~shaibal/leader.php</a>
- 2. Prof. Abhinav Kranti, Electrical Engineering, IIT Indore akranti@iiti.ac.in <a href="http://people.iiti.ac.in/~akranti/">http://people.iiti.ac.in/~akranti/</a>

## 9. Work experience (in chronological order).

## > Industrial Experience

Positions held	Name of the Institute	From	То	Pay Scale
1. Software Engineer	Verizon Data Services India (VDSI)	12-08-2009	03-12-2010	6.5 lacs per annum

**Role & Responsibilities:** Data-mining for Fios TV (Verizon, USA) for targeted marketing, implementing Lua scripts for Fios TV, web-services and web development/management

## > Entrepreneurship Experience

	Positions held	Name of the Institute	From	То	Pay Scale
1.	Senior Analyst	Vihar IT Solutions Pvt. Ltd.	03-03-2011	30-07-2013	Owner of company

Role & Responsibilities: Entrepreneurship experience, Company management, Technical consultancy for software and web solutions

## > Research Experience

	Positions held	Name of the Institute	From	То	Pay Scale
1.	CSIR, Junior Research Fellow (JRF)	Indian Institute of Technology (IIT) Indore	22 July 2014	July 2016	INR 25000.00 per month + HRA

**Role & Responsibilities:** Deposition & characterization of micro- and nano-structured materials, and to apply this knowledge in realizing advanced tools and devices

2.	CSIR,	Indian Institute of	July 2016	Jan 2019	INR 28000.00 per month +
	Senior Research	Technology (IIT)			HRA
	Fellow (SRF)	Indore			

 $\textbf{Role \& Responsibilities:} \ \ \text{Experimental fabrication, characterization, and modelling of RRAMs/Memristor for the application of non-volatile memory and neuromorphic applications$ 

3.	Postdoc Research	University of Utah	Jan 2019	Sep 2019	USD 55,000 per annum
	Scientist	USA			

Role & Responsibilities: Broadly doing research related to emerging device technologies, digital design, and design automation and specifically utilizing Non-Volatile Memories (NVMs) like Resistive Random Access Memory (RRAM) in reconfigurable logic circuits, such as Field-Programmable Gate Arrays (FPGAs)

4.	Postdoc Research	Indian Institute of Technology	Sep 2019	Feb 2020	INR 70000 per
	Scientist	Kanpur			month

**Role & Responsibilities:** Optimization of various parameters of solar cells and corresponding modelling to analyze various performance parameters.

## > Academic Experience

	Positions held	Name of the Institute	From	То	Pay Scale
1.	Assistant Professor	National Institute of Technology (NIT) Patna	Feb 2020	Till Present	Grade Pay, Level 11

**Role & Responsibilities:** Teaching and supervising laboratories of several subjects at Electrical Engineering Dept. as well working as in-charge of several institutional/departmental responsibilities and carrying out research in concerned field.

# 10. Professional Recognition/Award/Prize/Certificate/Fellowship received by the applicant.

#### Research Awards

1. **DST International Travel Support** to attend and present paper in 20th International Conference on Superlattices, Nanostructures and Nanodevices (ICSNN2018), Madrid, Spain, July 23-26, 2018

- 2. Best Presentation award, 6th International Symposium on Integrated Functionalities, December 10-13, 2017
- **3. CSIR International Travel Support** to attend and present paper in *Materials Research Society (MRS) Spring Meeting, Phoenix, Arizona, USA, April 2-6, 2018*
- MPCST International Travel Support to attend and present paper in 34th International Conference on the Physics of Semiconductors (ICPS 2018), Montpellier, France, 2018
- 5. Indian Institute of Kanpur, Institute Postdoc Fellowship Award to carry out research in Materials Science and Engineering Dept. for two years
- 6. DST National Postdoc Fellowship Award 2020

#### > Academic Achievements

	Name of Award	Awarding Agency	Year
1.	Autodesk Certified Professional (ACP) (Score: 957/1000, Certiport ID: 90065872)	Autodesk	2018
2.	Senior Research Fellowship	CSIR	2016- 19
3.	Junior Research Fellowship	CSIR	2014-16
4.	CSIR Fellowship award	CSIR	2014
5.	Sun Certified Java Programmer (SCJP) (Score: 90 %, Candidate ID: SR3198768 Registration ID:PC0SYD5218)	Sun Professional 3,	2008
6.	Cisco Certified Network Associate (CCNA) (Score: 947/1000 in Exam 640- 802, Cisco ID: CSCO11459282; Registration ID: 226180540)	Cisco	2008
7.	Cisco Certified Network Professional (CCNP), BSCI & BCMSN (Score: 981/ 1000 in Exam 642-892)	Cisco	2008

## > Certification Courses completed

	Name of Award	Awarding Agency	Year
1.	Reliability Engineering and Asset Management	Global Initiative of Academic Networks (GIAN), MHRD, India	2018
2.	Media Security and Forensics	Global Initiative of Academic Networks (GIAN), MHRD, India	2018
3.	Energy, Education, and Innovation	Global Initiative of Academic Networks (GIAN), MHRD, India	2018
4.	Advanced Pattern Recognition Techniques for Biometrics	Global Initiative of Academic Networks (GIAN), MHRD, India	2018
5.	Fundamentals of Solid State Physics: From Theoretical and Computational Concepts to Recent Applications in Information Technology	Global Initiative of Academic Networks (GIAN), MHRD, India	2018
6.	Economics of Science, Technology and Innovation: Empirical Approaches and Randomized Control Trials (RCTs)	Global Initiative of Academic Networks (GIAN), MHRD, India	2018

- 7. Inorganic chemistry of imaging: Magnetic Global Initiative of Academic Networks (GIAN), 2018 resonance and optical imaging with coordination MHRD, India complexes
- 8. Computationally Aided Materials Designing for Global Initiative of Academic Networks (GIAN), 2018
  Materials Genome MHRD, India

## 11. Projects

1.

#### Projects

Project Title	Sponsoring Agency Institute	From	То	Amount
Bio-inspired Electronic Synaptic Cells for Neuromorphic and Bio- medical applications	DST-SERB	Feb 2022	Till now	INR 28.5 Lakhs

[File No: <u>SRG/2021/002110</u>]

**Project Highlights:** The project works towards designing high-speed, high-density, highly-scalable, energy-efficient electronic synaptic cells, which can be utilized primarily for data storage and neuromorphic applications. It aims to identify and design an emerging non-volatile memory (NVM) technology, i.e., Memristor or Resistive Random Access Memory (RRAM) in the form of functional hybrid Memristor Crossbar-Array/CMOS System

**2.** DST Training Program on DST July 2021 Till Now INR 3.6 Lakhs Entrepreneurship

**Project Highlights:** DST Training Program on Entrepreneurship through Innovation and Entrepreneurship Division and Training Program on Entrepreneurship Scheme

## 13. Any other Information (maximum 500 words)

## > Internship/training

	Name of company	Purpose	Year
1.	Jetking Newdelhi	To install, configure, operate, and troubleshoot medium-size routed an switched networks, including implementation and verification of connection to remote sites in a WAN(wide area network)	
2.	Uttar Pradesh Power Corporation Limited (UPPCL), Azamgarh	Summer training at a sub-station of UPPCL, Azamgarh for around eight weeks	2009

#### > Technical workshop/events attended/invited

	Name of Workshop/Events	Organizing Agency	Year
1.	Engineering Education & Research Seminar, Radisson Blu Indore, India November 27, 2017 (Invited)	National Instruments	2017
2.	Friends of MP Conclave, Hotel Marriott, Indore, Jan. 3-4 2018 (Invited)	Govt. of Madhya Pradesh, India	2018
3.	18th International Workshop on The Physics of Semiconductor Devices (18th IWPSD), IISc, Bangalore, India, December 7-10, 2015	IWPSD	2015

## > Social activities

	Name of Award	Awarding Agency	Year
1.	Rashtriya Avishkar Abhyan, Teaching Portal	Ministry of Human Resource and Development	2016
2.	Swachh Bharat Summer Internship 2018 Summer Internship	Unnat Bharat Abhiyan	2018

## > Extra-curricular activities

	Name of Award	Awarding Agency	Year
1.	Yoga Therapy certification	DAVV, Govt. of Madhya-Pradesh	2018
2.	4 <sup>th</sup> Edition Indore Marathon, 10 km	Academy of Indore Marathoners	2018
3.	Lotus 10k Run 2018	Indore Super Chargers	2018
4.	Cycle Marathon 50 km , 2018	Youjustrun	2018

## > Affiliation to Professional Organizations

	Name of Organization	Affiliation status
1.	IEEE	Member (94148943)
2.	Indian Laser Association	Life Member (LM-1262)
3.	VIBHA (Vijnana Bharati)	Life Member (21101)
4.	Plasma Science Society of India (PSSI)	Life member (LM-1542)
5.	The Institute of Engineers (India)	Chartered Engineer (AM1839643)
6.	Indian Science Congress Association, ISCA, India	a Life Member (L37164)

- 7. Material Research Society, USA Member (phd1401102003)

## **Technical reviewer in journals**

Name of journal

- 1. **IEEE: Transactions on Nanotechnology**
- 2. **AIP: Applied Physics Letters**
- 3. IEEE: Transactions on Computer-Aided Design of Integrated Circuits and Systems
- 4. **IET: Circuits, Devices & Systems**
- 5. Wiley: Advanced Electronics Materials
- 6. **Elsevier : Superlattices and Microstructures**

## 7. AIP: Journal of Applied Physics

#### Scientific contributions in magazines

Name of Magazine

#### 1. Brainfeed Higher Education Plus

## Nanodevice fabrication/processing/characterization/modelling expertise

#### 1. Device fabrication techniques

a) Dual Ion Beam Sputtering (DIBS), b) Electrodeposition, c) Hydrothermal method d) Spin-coating

#### 2. Device processing methods

a) Rapid Thermal Processing (RTP) Annealing

## 3. Device characterization instruments hands-on

- a) Keithley 4200A-SCS Parameter Analyzer, b) Keithley 2612A Sourcemeter, c) B1500 Keysight,
- d) Hioki 3532-50 LCR Hi-Tester, e) Variable-angle/wavelength Spectroscopic Ellipsometry,
- f) Cryogenic Vacuum Probe-station, g) Quantum Efficiency Measurement System, h) Solar Simulator System.

#### 4. Device modelling software experience

Matlab, COMSOL, Silvaco, Orcad-PSPICE, Quantum espresso

#### 5. Designing masks for semiconductor devices

AUTOCAD

#### 6. Device design (Digital design) and automation

**PSPICE** 

## 7. Device (Wafer/die) packaging

Wire-bonding (MEI1204W)

#### 8. Device (Wafer/die) testing

Probe-card (GGB), Probe-station, B1500 Semiconductor Device Parameter Analyzer

#### Other technical skills

#### 1. Software skills

C, Data Structure, Core Java (SCJP 5.0) J2EE( servlets, jsp), C#.net

#### 2. Website building

PHP, Javascript, Asp.net, HTML

#### 3. Database management system

Sql-server 2008

#### 4. Networking

LAN management

- 1. Routing: Routing protocols (RIP, EIGRP, OSPF, BGP), IP multicast design models
- 2. Switching: Campus network model, STP, VLAN, multilayer switching, switch security

#### WLAN management

Access Points (AP), Lightweight AP operation, AP association and roaming

#### **Important Research Achievements**

- 1. Using cost-effective Al electrode against expensive Pt electrodes to give Non-volatile Memory (NVM) Solution
- 2. Evading the process of electroforming in RRAM using material engineering methods to give highperformance NVMs
- 3. Universal and novel analytical model of RRAM to design RRAMs using wide range of switching materials and electrodes
- 4. Creating a Cluster-Based Routing Protocol for Mobile Adhoc Networks (MANETs) to establish adhoc networks in any isolated area devoid of network infrastructure
- 5. Organic material based RRAM device to give an eco-friendly Non-Volatile Memory (NVM) solution

Organizing important research seminar, workshop etc.

1. FDP course "Next-Generation Semiconductor Devices for high-end applications" (22<sup>nd</sup>-27<sup>th</sup> June 2020) was organized at Dept. of Electrical Engineering, NIT Patna

Coordinator: Dr. Amitesh Kumar

2. FDP course "Renewable Energy: Research to Industry " (22<sup>nd</sup>-Aug. 13<sup>th</sup> Sep. 2020) was organized at Dept. of Electrical Engineering, NIT Patna

Coordinator: Dr. Amitesh Kumar

FDP course "Electrical Vehicles and Mobility " from 24-01-2022 to 04-02-2022 was jointly organized by NIT Patna, MNIT Jaipur, IIIT Jabalpur

Coordinator: Dr. Amitesh Kumar (NIT Patna)

FDP course Next-generation Applications in Electrical and Electronics Engineering" from 15th September to 20th September "from 24-01-2022 to 04-02-2022 was organized at Dept of Electrical Engineering, NIT Patna

Coordinator: Dr. Amitesh Kumar (NIT Patna)

5. FDP course "Blockchain Technology for Next-Generation Applications" from 19th June 24th June 2023 was organized at Dept of Electrical Engineering, NIT Patna

Coordinator: Dr. Amitesh Kumar (NIT Patna)

FDP course "Research Methodology For Social Sciences, Engineering and Management: NEP 2020 (RMSSEM 2023)" from 10th July- 14th July 2023 was organized NIT Patna

**Coordinator: Dr. Amitesh Kumar (NIT Patna)** 

#### **Ongoing Project**

1. Project Title: Bio-Inspired Synaptic Cells for Neuromorphic and Biomedical Applications

Project File No: SRG/2021/002110

Funding Agency: Department of Science & Technology

Amount of Project: 2900000.00

#### Collaborative work with different groups

1. Hybrid Nanoelectronics Research Group

2.	RMIT, Australia	Micro/nano fabrication facility
3.	Shinshu University, Japan.	HR-TEM
4.	Low Power Nanoelectronics Research Group, IIT, Indore	Modelling and simulation (Ph.D. Lab)
5.	Supramolecular Chemical Nanoscience Group, IIT Indore	Organic material synthesis
6.	RRCAT, Indore	Beamline facility
7.	SNU, Noida	AFM facility

Place: NIT Patna, India Signature

Aprilesh Glumar

# **List of Publications/Projects**

List of	Project/Publications/Conference Proceedings/Patents/Book Chapters
i)	List of Projects (Running)
	Project Title : Bio-Inspired Synaptic Cells for Neuromorphic and Biomedical Applications
	Project File No: SRG/2021/002110
	Funding Agency: Department of Science & Technology
	Amount of Project: 2900000.00
ii)	Google Scholar Profile
	Citations 564 h-index 13 i10-index 16
	Q1 Journals: 19 Q2 Journals: 14 Q3 Journals: 1
iii)	List of Patents (Granted)
1	Dual-ion beam sputtered cost-effective and non-volatile resistive memory devices Inventors: Shaibal Mukherjee and <b>Amitesh Kumar</b> , Patent Application No. 201621020046, March 24, 2023 (Status: Granted)
2.	A System For Maximum Power Optimization Of Fuel Cell Inventors: <b>Amitesh Kumar</b> and Balmukund Kumar Patent Application No. 202331026979, October 10, 2023 (Status: Granted).
iv)	List of Patents (Published)
3.	A Field Effect Transistor Based Biosensor Device For Detection Of Cancer Cell, <i>Application No.: 202331035246</i> , Inventors: <b>Amitesh Kumar</b> , Anirban Kolay, <i>Filed Date: 19<sup>th</sup> May 2023</i> , (Status: Published)
4.	П-Conjugated Compound For Resistive Switching Device, and method of fabrication Inventors: Apurba K. Das, Shaibal Mukherjee, Rohit Jadhav and <b>Amitesh Kumar</b> , Patent Application No. 201921027542, Jan 15, 2021 (Status: Published).
v)	Publications in International Journals
1.	Anirban Kolay; Amitesh Kumar Liver cancer rapid-testing POC low-cost diagnostic unit using novel dual-gate source-extended TFET based biosensor. Sensors Actuators A. Phys. 369, 115131 (2024). Sensors and Actuators: A. Physical (Impact factor: 4.6, Q1) https://doi.org/10.1016/j.sna.2024.115131
2.	Reetwik Bhadra, Ramesh Kumar, Amitesh Kumar, Device Engineering of Dual Metal Gate-based Artificial Synapse for Enhanced Plasticity utilizing Al2O3 based Ion Conducting Electrolyte" IEEE Transactions on Electron Devices, 2024 (Impact factor: 3.1 Q2) (DOI: 10.1109/TED.2024.3367663).
3.	Rahul Kumar, Amitesh Kumar, Effective-diode-based analysis of industrial solar photovoltaic panel by utilizing novel three-diode solar cell model against conventional single and double solar cell. Environmental Science and Pollution, 2024 DOI:10.1007/s11356-024-32474-z. (Impact factor: 5.8, Q1)
4.	Pritam Kumar and <b>Amitesh Kumar</b> , Device engineering of lead-free double perovskite (Cs 4 CuSb 2 Cl 12 & Cs 2 AgBiBr 6 )/crystalline silicon high-performance eco-friendly tandem solar cells, <b>Silicon</b> , 2024 ( <b>Impact factor: 2.9, Q2</b> )
5.	Parshuram Singh, Amitesh Kumar, Device Engineering of Highly-Efficient Eco-Friendly Novel FASnI <sub>3</sub> Based Tandem Photovoltaic Cells. Silicon (2023) (Impact factor: 2.9 Q2). <a href="https://doi.org/10.1007/s12633-023-02717-8">https://doi.org/10.1007/s12633-023-02717-8</a>
6.	Pritam Kumar and <b>Amitesh Kumar</b> , High - performance optimization and analysis of Cs 2 AgBiBr 6 - based lead - free double perovskite solar cells, <b>Journal of Materials Science: Materials in Electronics</b> . 34, 1810 (2023), <a href="https://doi.org/10.1007/s10854-023-11225-9">https://doi.org/10.1007/s10854-023-11225-9</a> ( <b>Impact Factor:</b> 2.8 <b>Q2</b> )

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7.	Parshuram Singh, Amitesh Kumar, Device engineering of double perovskite based solar cells towards high-performance, eco-friendly solar cells, Optical and Quantum Electronics 55 (4), 304 <a href="https://doi.org/10.1007/s11082-023-04580-8">https://doi.org/10.1007/s11082-023-04580-8</a> (Impact Factor: 2.79 Q2)
8.	Anirban Kolay; Amitesh Kumar A Novel Liver Cancer POC Diagnostic Detection Technique by a Gate-engineered Source-extended TFET Device. Medical Engineering and Physics (Impact factor: 2.2 Q3)
9.	Chinmay Bera, Rajib Kumar Mandal, <b>Amitesh Kumar</b> . A Novel Redacted Extended Kalman Filter and Fuzzy Logic-Based Technique for Measurement of State-of-Charge of Lithium-Ion Battery. Journal of Electrochemical Energy Conversion and Storage. 2024 Nov 1;21(4) ( <b>Impact factor: 2.5 Q2</b> )
10.	Pritam Kumar and <b>Amitesh Kumar</b> , Design And Optimization Of High-Performance Eco-Friendly Perovskite Solar Cells: Utilizing Famasngei3 & Csgei3 As Absorbers And Tuning HTL & Interface Parameters, <b>International Journal of Modern Physics B</b> . ( <b>Impact factor: 2.0 Q2</b> )
11.	Balmukund Kumar, Amitesh Kumar, A Novel Adaptive Flower Pollination Algorithm for Maximum Power Tracking of Photovoltaic Systems under Dynamic Shading Conditions", Iranian Journal of Science and Technology, Transactions of Electrical Engineering, (Impact factor: 2.0 Q2)
12.	Deepti, P. S. Mondal, C. Pal, <b>Amitesh Kumar</b> , and S. Majumder, "Label-free ultrasensitive electrochemical dopamine sensor fabrication using a low-cost pencil graphite electrode," <i>Colloids And Surfaces A-Physicochemical And Engineering Aspects. Eng. Asp.</i> , vol. 671, no. February, p. 131630, 2023, <a href="https://doi.org/10.1016/j.colsurfa.2023.131630">https://doi.org/10.1016/j.colsurfa.2023.131630</a> . ( <b>Impact factor: 5.2 Q1</b> )
13.	Sanjay Kumar, D. Kumbhar; Mayank Dubey, <b>Amitesh Kumar</b> , Tukaram D. Dongale, Somanath D. Pawar, and Shaibal Mukherjee Exploring Statistical Approaches for Accessing the Reliability of Y2O3-based Memristive Devices, <b>Microelectronic Engineering</b> , ( <b>Impact factor: 2.3 Q2</b> )
14.	Aaryashree, Pratik V. Shinde, <b>Amitesh Kumar</b> , Dattatray J. Late and Chandra Sekhar Rout, <i>Recent advances in 2D black phosphorus based materials for gas sensing applications</i> , <b>J. Mater. Chem. C</b> , Vol. 9, pp. 3773-3794, Feb. 2021, <u>10.1039/D0TC05565D</u> ( <b>Impact factor: 7.05 Q1</b> )
15.	Mangal Das, <b>Amitesh Kumar</b> , Sanjay Kumar, Biswajit Mandal, Gaurav Siddharth, Pawan Kumar, Myo Than Htay, and Shaibal Mukherjee, <i>Impact of interfacial SiO2 on dual ion beam sputtered Y2O3-based memristive system</i> , <b>IEEE Transactions on Nanotechnology</b> , vol. 19, no. 153134, pp. 332-337, May 1, 2020 ( <b>Impact Factor: 2.86 Q2</b> ) <u>10.1109/TNANO.2020.2987200</u>
16.	Mangal Das, <b>Amitesh Kumar</b> , Sanjay Kumar, Biswajit Mandal, Md Arif Khan and Shaibal Mukherjee, <i>Effect of Surface Variations on the Performance of Yttria based Memristive System</i> , <b>IEEE Electron Device Letters</b> , vol. 39, no. 12, pp. 1852-1855, December 2018. ( <b>Impact factor: 3.43 Q1</b> ) 10.1109/LED.2018.2878953
17.	Brajendra S. Sengar, Vivek Garg, <b>Amitesh Kumar</b> , Praveen Dwivedi, <i>Numerical Simulation: Design of High-Efficiency Planar p-n Homojunction Perovskite Solar Cells</i> , <b>IEEE Transactions on Electron Devices</b> , Volume: 68, Issue: 5, pp. 2360 - 2364, March 2021, <b>IEEE</b> , DOI: <u>10.1109/TED.2021.3066454</u> ( <b>Impact factor: 3.1 Q2</b> )
18.	Brajendra S. Sengar, Vivek Garg, Gaurav Siddharth, <b>Amitesh Kumar</b> , Sushil Kumar Pandey, Mayank Dubey VictorV. Atuchin, Shailendra Kumar, and Shaibal Mukherjee, <i>Improving the Cu2ZnSn(S,Se)4-based photovoltaic conversion efficiency by back contact modification</i> , <b>IEEE Transactions on Electron Devices</b> , Volume: 68, Issue 6, pp. 2748 – 2752, April 2021, <b>IEEE</b> , DOI: <a href="https://doi.org/10.1109/TED.2021.3071105">10.1109/TED.2021.3071105</a> ( <b>Impact factor: 3.1 Q2</b> )
19.	Md Arif Khan, Rohit Singh, Ritesh Bhardwaj, <b>Amitesh Kumar</b> , Amit Kumar Das, Pankaj Misra, Abhinav Kranti and Shaibal Mukherjee, <i>Enhanced sheet charge density in DIBS grown CdO alloyed ZnO buffer based heterostructure</i> , <b>IEEE Electron Device Letters</b> , vol. 39, issue 6, pp. 1-4, June 2018. ( <b>Impact factor: 3.048 Q1</b> ) 10.1109/LED.2018.2829761
20.	Praveen Dwivedi, Rohit Singh, Brajendra S. Sengar, <b>Amitesh Kumar</b> , Vivek Garg, <i>A New Simulation Approach of Transient Response to Enhance the Selectivity and Sensitivity in Tunneling Field Effect Transistor-Based Biosensor</i> , <b>IEEE Sensors</b> , Volume: 21, Issue: 3, pp. 3201 - 3209, Feb 2021, <b>IEEE</b> , DOI: 10.1109/JSEN.2020.3028153 ( <b>Impact factor: 2.36 Q1</b> )
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21.	Vivek Garg, Brajendra S. Sengar, Pankaj Sharma, <b>Amitesh Kumar</b> , Aaryashree, Shailendra Kumar, Shaibal Mukherjee, <i>Sputter-instigated plasmon-enhanced optical backscattering layer in ultrathin solar cells: Application of GZO in CIGSe material system</i> , <b>Solar Energy</b> , vol. 174, pp. 35-44, September 2018. ( <b>Impact factor: 4.37 Q1</b> ) <a href="https://doi.org/10.1016/j.solener.2018.08.074">https://doi.org/10.1016/j.solener.2018.08.074</a>
22.	Vivek Garg, Brajendra S. Sengar, Vishnu Awasthi, <b>Amitesh Kumar</b> , Rohit Singh, Shailendra Kumar, C. Mukherjee, V. V. Atuchin, and Shaibal Mukherjee, <i>Investigation of dual-ion beam sputter-instigated plasmon generation in TCOs: A case study of GZO</i> , <b>ACS Applied Materials and Interfaces</b> , vol. 10, no. 6, pp. 5464–5474, January 2018. ( <b>Impact factor: 7.5 Q1</b> ) <a href="https://doi.org/10.1021/acsami.7b15103">https://doi.org/10.1021/acsami.7b15103</a>
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